

(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property
Organization
International Bureau



10/521397



(43) International Publication Date
29 January 2004 (29.01.2004)

PCT

(10) International Publication Number
WO 2004/010212 A1

(51) International Patent Classification⁷: G02F 1/1337

(21) International Application Number:
PCT/KR2002/001782

(22) International Filing Date:
19 September 2002 (19.09.2002)

(25) Filing Language: Korean

(26) Publication Language: English

(30) Priority Data:
2002/42658 19 July 2002 (19.07.2002) KR

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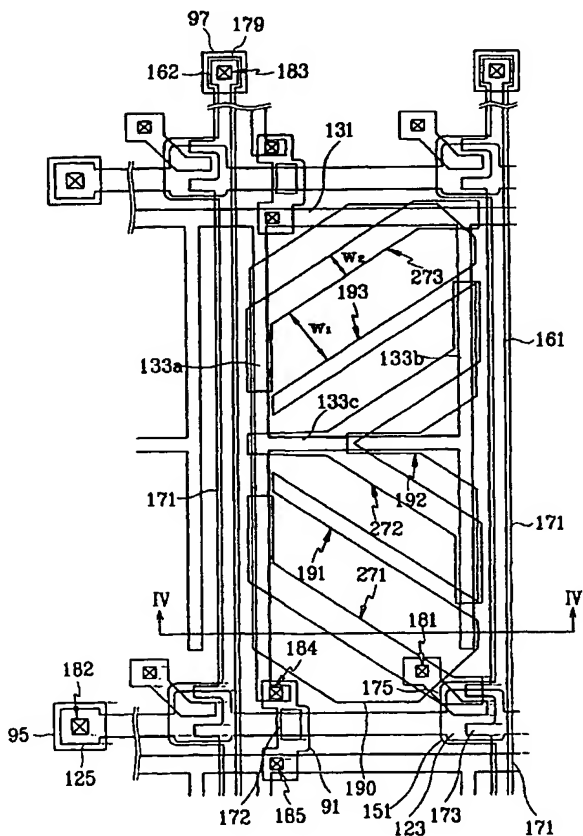
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(81) Designated States (national): AE, AG, AL, AM, AT, AU,
AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU,
CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH,
GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KZ, LC, LK,
LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX,
MZ, NO, NZ, OM, PH, PL, PT, RO, RU, SD, SE, SG, SI,
SK, SL, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC,
VN, YU, ZA, ZM, ZW.

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(54) Title: VERTICALLY ALIGNED MODE LIQUID CRYSTAL DISPLAY



(57) Abstract: A liquid crystal display is provided, which includes: a first insulating substrate; a gate line formed on the first insulating substrate; a gate insulating layer formed on the gate line; a data line formed on the gate insulating layer; a passivation layer formed on the data line; a pixel electrode formed on the passivation layer and a first cutout pattern; a second insulating substrate facing the first insulating substrate; and a common electrode formed on the second insulating substrate and having a second cutout pattern, wherein width of the domains is equal to or less than 30 microns.